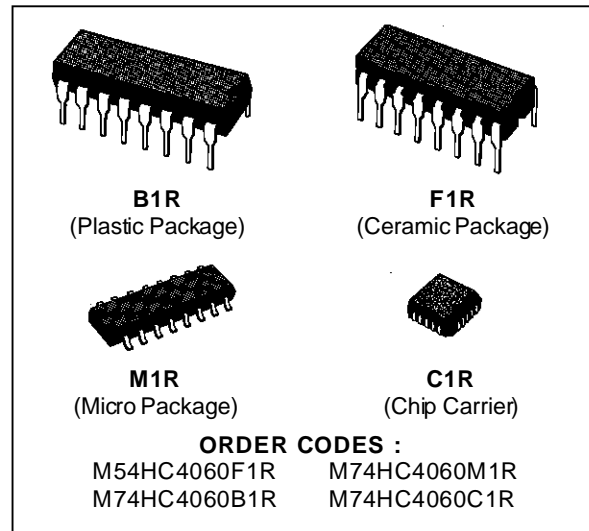


14 STAGE BINARY COUNTER/OSCILLATOR

- HIGH SPEED
f_{MAX} = 58 MHz (TYP.) AT V_{CC} = 5 V
- LOW POWER DISSIPATION
I_{CC} = 4 μA (MAX.) AT T_A = 25 °C
- HIGH NOISE IMMUNITY
V_{NIH} = V_{NIL} = 28 % V_{CC} (MIN.)
- OUTPUT DRIVE CAPABILITY
10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
|I_{OH}| = I_{OL} = 4 mA (MIN.)
- BALANCED PROPAGATION DELAYS
t_{PLH} = t_{PHL}
- WIDE OPERATING VOLTAGE RANGE
V_{CC} (OPR) = 2 V TO 6 V
- PIN AND FUNCTION COMPATIBLE
WITH 4060B



DESCRIPTION

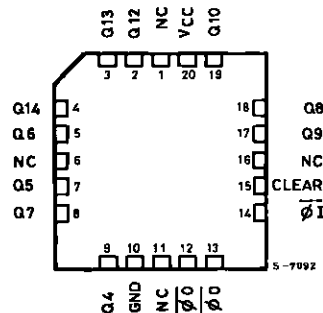
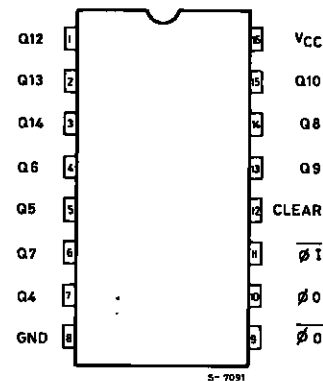
The M54/74HC4060 is a high speed CMOS 14-STAGE BINARY COUNTER/OSCILLATOR fabricated in silicon gate C²MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption. It operates ten times faster than metal-gate C²MOS IC (4060B) with the same power dissipation.

The oscillator configuration allows design of either RC or crystal oscillator circuits. A high level on the CLEAR accomplishes the reset function, i.e. all counter outputs are made low and the oscillator is disabled.

A negative transition on the clock input increments the counter. Ten kinds of divided output are provided ; 4 to 10 and 12 to 14 stage inclusive. The maximum division available at Q12 is 1/16384 f oscillator.

The $\overline{\phi}_1$ input and the CLEAR input are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTIONS (top view)



NC =
No Internal
Connection

M54/M74HC4060

INPUT AND OUTPUT EQUIVALENT CIRCUIT

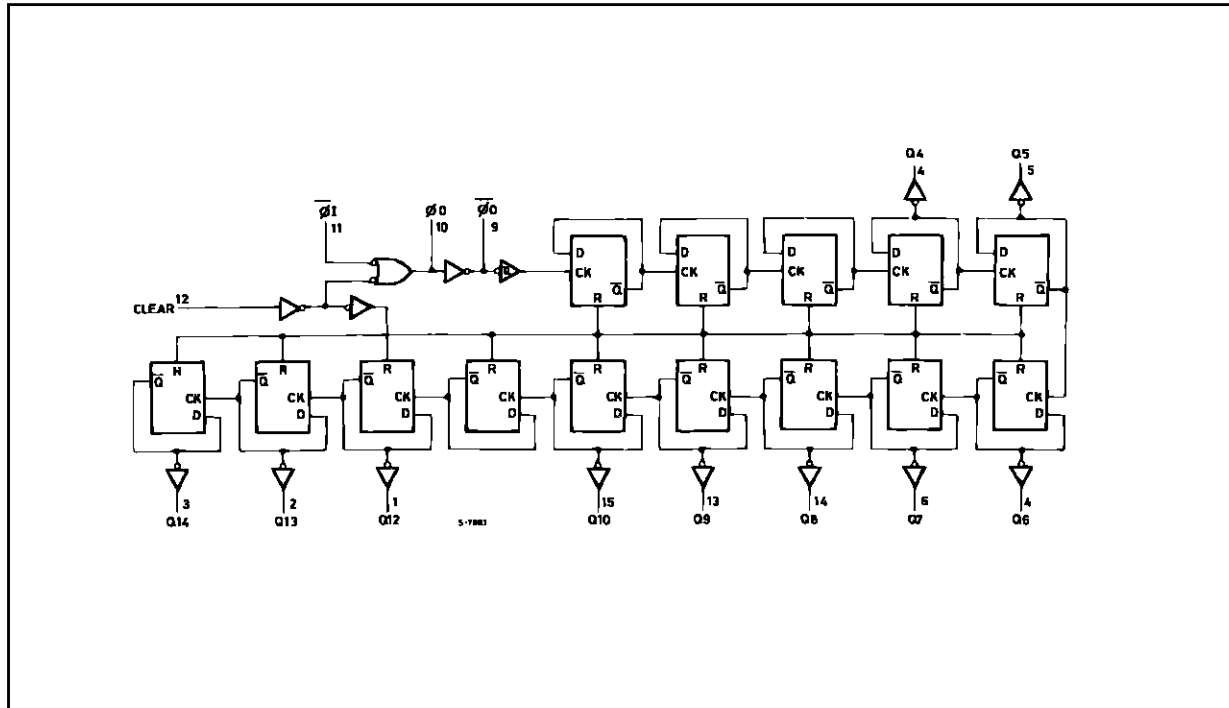


TRUTH TABLE

| $\overline{\phi 1}$ | CLEAR | FUNCTION |
|---------------------|-------|--|
| X | H | COUNTER IS RESET TO ZERO STATE $\phi 0$ OUTPUT GOES TO HIGH LEVEL $\overline{\phi 0}$ OUTPUT GOES TO LOW LEVEL |
| | L | COUNT UP ONE STEP |
| | L | NO CHANGE |

X: DON'T CARE

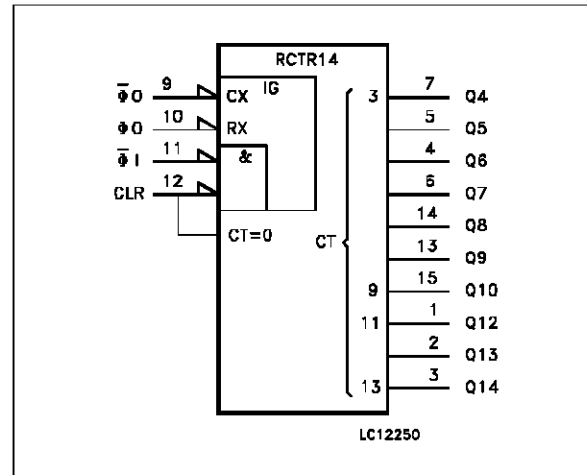
LOGIC DIAGRAM



PIN DESCRIPTION

| PIN No | SYMBOL | NAME AND FUNCTION |
|------------------------|---------------------|-------------------------------|
| 1, 2, 3 | Q12 to Q14 | Counter Outputs |
| 7, 5, 4, 6, 14, 13, 15 | Q4 to Q10 | Counter Outputs |
| 9 | $\overline{\phi O}$ | External Capacitor Connection |
| 10 | ϕO | External Resistor Connection |
| 11 | $\overline{\phi I}$ | Clock Input/Oscillator Pin |
| 12 | CLEAR | Master Reset |
| 8 | GND | Ground (0V) |
| 16 | V _{CC} | Positive Supply Voltage |

IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-------------------------------------|--|-------------------------------|------|
| V _{CC} | Supply Voltage | -0.5 to +7 | V |
| V _I | DC Input Voltage | -0.5 to V _{CC} + 0.5 | V |
| V _O | DC Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | ± 20 | mA |
| I _{OK} | DC Output Diode Current | ± 20 | mA |
| I _O | DC Output Source Sink Current Per Output Pin | ± 25 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | ± 50 | mA |
| P _D | Power Dissipation | 500 (*) | mW |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| T _L | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.
 (*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit | |
|---------------------------------|---|---|-----------------------------------|----|
| V _{CC} | Supply Voltage | 2 to 6 | V | |
| V _I | Input Voltage | 0 to V _{CC} | V | |
| V _O | Output Voltage | 0 to V _{CC} | V | |
| T _{op} | Operating Temperature: M54HC Series M74HC Series | -55 to +125 -40 to +85 | °C °C | |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 2 V V _{CC} = 4.5 V V _{CC} = 6 V | 0 to 1000 0 to 500 0 to 400 | ns |

DC SPECIFICATIONS

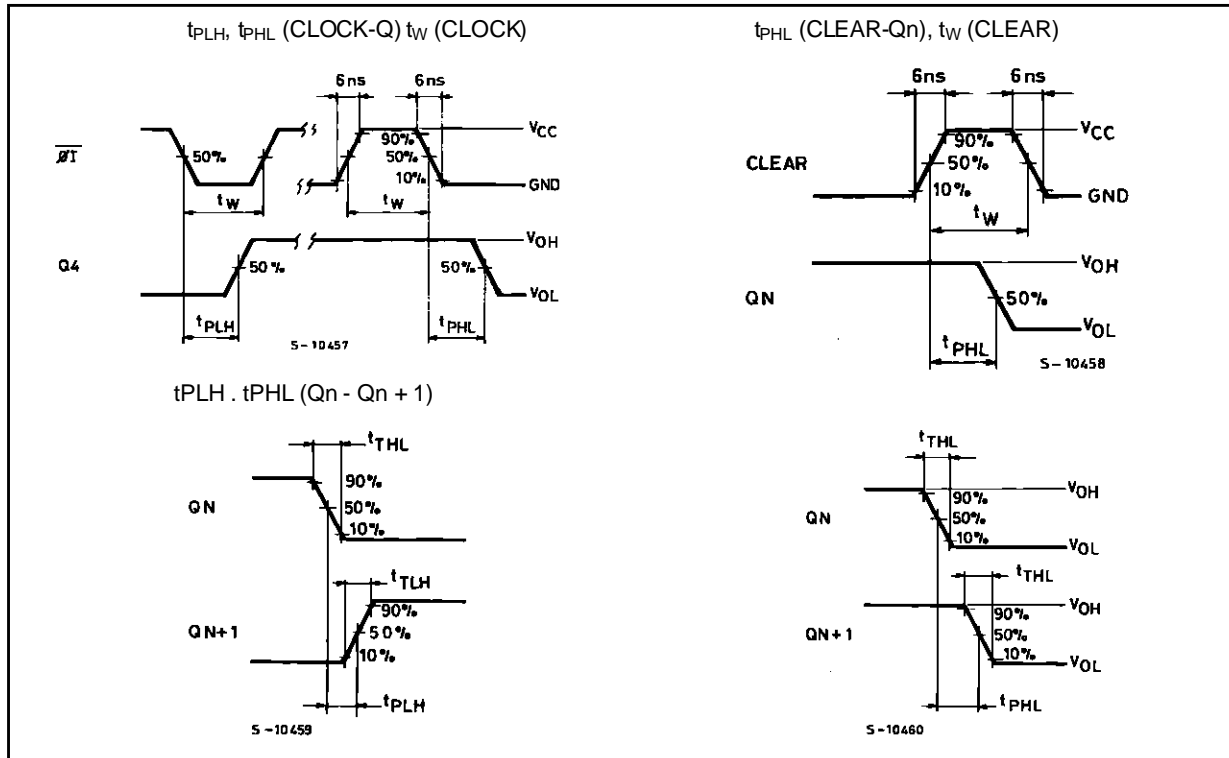
| Symbol | Parameter | Test Conditions | | Value | | | | | | Unit | | |
|-----------------|---|------------------------|---|---|------|------|----------------------|------|-----------------------|------|------|---|
| | | V _{CC} (V) | | T _A = 25 °C 54HC and 74HC | | | -40 to 85 °C 74HC | | -55 to 125 °C 54HC | | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. | |
| V _{IH} | High Level Input Voltage | 2.0 | | 1.5 | | | 1.5 | | 1.5 | | V | |
| | | 4.5 | | 3.15 | | | 3.15 | | 3.15 | | | |
| | | 6.0 | | 4.2 | | | 4.2 | | 4.2 | | | |
| V _{IL} | Low Level Input Voltage | 2.0 | | | | 0.5 | | 0.5 | | 0.5 | V | |
| | | 4.5 | | | | 1.35 | | 1.35 | | 1.35 | | |
| | | 6.0 | | | | 1.8 | | 1.8 | | 1.8 | | |
| V _{OH} | High Level Output Voltage (Q Outputs) | 2.0 | V _I = V _{IH} or V _{IL} | I _O = -20 μA | 1.9 | 2.0 | | 1.9 | | 1.9 | V | |
| | | 4.5 | | | 4.4 | 4.5 | | 4.4 | | 4.4 | | |
| | | 6.0 | | | 5.9 | 6.0 | | 5.9 | | 5.9 | | |
| | | 4.5 | | I _O = -4.0 mA | 4.18 | 4.31 | | 4.13 | | 4.10 | | |
| | | 6.0 | | I _O = -5.2 mA | 5.68 | 5.8 | | 5.63 | | 5.60 | | |
| V _{OL} | Low Level Output Voltage (Q Outputs) | 2.0 | V _I = V _{IH} or V _{IL} | I _O = 20 μA | | 0.0 | 0.1 | | 0.1 | | 0.1 | V |
| | | 4.5 | | | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 6.0 | | | | 0.0 | 0.1 | | 0.1 | | 0.1 | |
| | | 4.5 | | I _O = 4.0 mA | | 0.17 | 0.26 | | 0.33 | | 0.40 | |
| | | 6.0 | | I _O = 5.2 mA | | 0.18 | 0.26 | | 0.33 | | 0.40 | |
| V _{OH} | High Level Output Voltage (øO, øO Output) | 2.0 | V _I = V _{IH} or V _{IL} | I _O = -20 μA | 1.8 | 2.0 | | 1.8 | | 1.8 | V | |
| | | 4.5 | | | 4.4 | 4.5 | | 4.0 | | 4.0 | | |
| | | 6.0 | | | 5.5 | 5.9 | | 5.5 | | 5.5 | | |
| V _{OL} | Low Level Output Voltage (øO, øO Output) | 2.0 | V _I = V _{IH} or V _{IL} | I _O = 20 μA | | 0.0 | 0.2 | | 0.2 | | 0.2 | V |
| | | 4.5 | | | | 0.0 | 0.5 | | 0.5 | | 0.5 | |
| | | 6.0 | | | | 0.1 | 0.5 | | 0.5 | | 0.5 | |
| I _I | Input Leakage Current | 6.0 | V _I = V _{CC} or GND | | | ±0.1 | | ±1 | | ±1 | μA | |
| I _{CC} | Quiescent Supply Current | 6.0 | V _I = V _{CC} or GND | | | 4 | | 40 | | 80 | μA | |

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

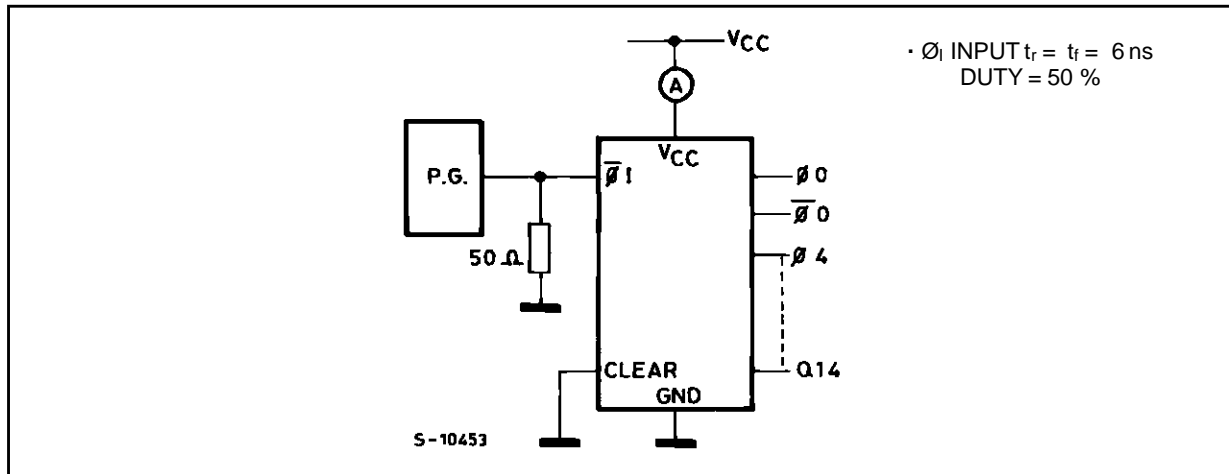
| Symbol | Parameter | Test Conditions | | Value | | | | | | Unit | |
|--|---|------------------------|--|---|------|------|----------------------|------|-----------------------|------|------|
| | | V _{CC} (V) | | T _A = 25 °C 54HC and 74HC | | | -40 to 85 °C 74HC | | -55 to 125 °C 54HC | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | Max. |
| t _{TLH} t _{THL} | Output Transition Time | 2.0 | | | 30 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 8 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 7 | 13 | | 16 | | 19 | |
| t _{PLH} t _{PHL} | Propagation Delay Time (ø1 - Q4) | 2.0 | | | 170 | 300 | | 375 | | 450 | ns |
| | | 4.5 | | | 41 | 60 | | 75 | | 90 | |
| | | 6.0 | | | 30 | 51 | | 64 | | 76 | |
| t _{PD} | Propagation Delay Time Difference (Qn- Qn+1) | 2.0 | | | 32 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 7 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 5 | 13 | | 16 | | 19 | |
| t _{PLH} t _{PHL} | Propagation Delay Time (CLEAR - Qn) | 2.0 | | | 85 | 195 | | 245 | | 295 | ns |
| | | 4.5 | | | 23 | 39 | | 49 | | 59 | |
| | | 6.0 | | | 17 | 33 | | 42 | | 50 | |
| f _{MAX} | Maximum Clock Frequency | 2.0 | | | 6 | 12 | | 5 | | 4 | ns |
| | | 4.5 | | | 30 | 50 | | 24 | | 20 | |
| | | 6.0 | | | 35 | 65 | | 28 | | 24 | |
| t _{W(H)} t _{W(L)} | Minimum Pulse Width (ø1) | 2.0 | | | 30 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 8 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 7 | 13 | | 16 | | 19 | |
| t _{W(H)} | Minimum Pulse Width (CLEAR) | 2.0 | | | 30 | 75 | | 95 | | 110 | ns |
| | | 4.5 | | | 8 | 15 | | 19 | | 22 | |
| | | 6.0 | | | 7 | 13 | | 16 | | 19 | |
| t _{REM} | Minimum Removal Time | 2.0 | | | 40 | 100 | | 125 | | 150 | ns |
| | | 4.5 | | | 10 | 20 | | 25 | | 30 | |
| | | 6.0 | | | 9 | 17 | | 21 | | 26 | |
| C _{IN} | Input Capacitance | | | | 5 | 10 | | 10 | | 10 | pF |
| C _{PD} (*) | Power Dissipation Capacitance | | | | 27 | | | | | | pF |

(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST CIRCUIT

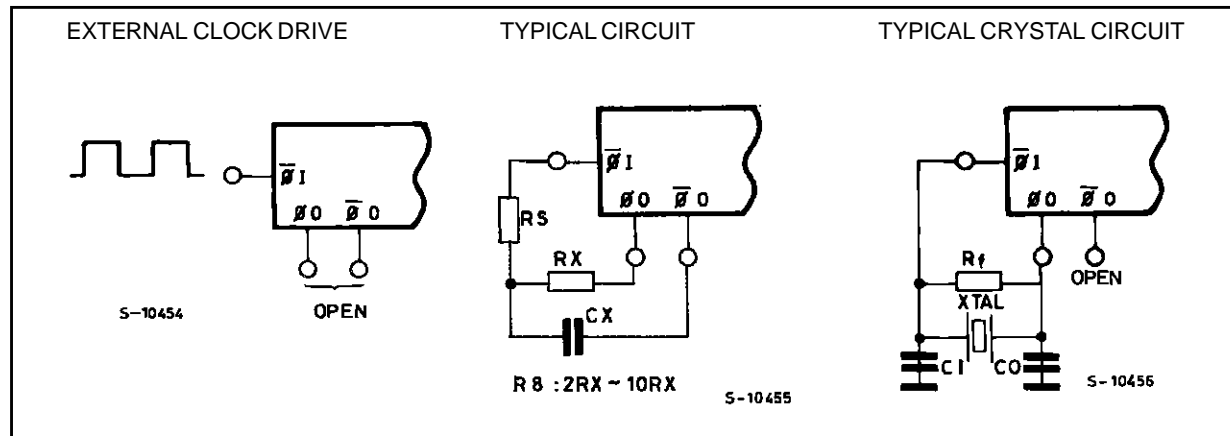


TEST CIRCUIT I_{CC} (Opr.)



Note : When CR or crystal oscillation circuit is adopted, the dynamic power dissipation will be greater than the measured value from the test circuit shown left, because these oscillation circuits spend much supply current.

TYPICAL CLOCK DRIVE CIRCUITS



Plastic DIP16 (0.25) MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| a1 | 0.51 | | | 0.020 | | |
| B | 0.77 | | 1.65 | 0.030 | | 0.065 |
| b | | 0.5 | | | 0.020 | |
| b1 | | 0.25 | | | 0.010 | |
| D | | | 20 | | | 0.787 |
| E | | 8.5 | | | 0.335 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 17.78 | | | 0.700 | |
| F | | | 7.1 | | | 0.280 |
| I | | | 5.1 | | | 0.201 |
| L | | 3.3 | | | 0.130 | |
| Z | | | 1.27 | | | 0.050 |



P001C

Ceramic DIP16/1 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|-------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 20 | | | 0.787 |
| B | | | 7 | | | 0.276 |
| D | | 3.3 | | | 0.130 | |
| E | 0.38 | | | 0.015 | | |
| e3 | | 17.78 | | | 0.700 | |
| F | 2.29 | | 2.79 | 0.090 | | 0.110 |
| G | 0.4 | | 0.55 | 0.016 | | 0.022 |
| H | 1.17 | | 1.52 | 0.046 | | 0.060 |
| L | 0.22 | | 0.31 | 0.009 | | 0.012 |
| M | 0.51 | | 1.27 | 0.020 | | 0.050 |
| N | | | 10.3 | | | 0.406 |
| P | 7.8 | | 8.05 | 0.307 | | 0.317 |
| Q | | | 5.08 | | | 0.200 |



SO16 (Narrow) MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.004 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | | 0.5 | | | 0.019 | |
| c1 | 45° (typ.) | | | | | |
| D | 9.8 | | 10 | 0.385 | | 0.393 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 8.89 | | | 0.350 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| M | | | 0.62 | | | 0.024 |
| S | 8° (max.) | | | | | |



P013H

PLCC20 MECHANICAL DATA

| DIM. | mm | | | inch | | |
|------|------|------|-------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 9.78 | | 10.03 | 0.385 | | 0.395 |
| B | 8.89 | | 9.04 | 0.350 | | 0.356 |
| D | 4.2 | | 4.57 | 0.165 | | 0.180 |
| d1 | | 2.54 | | | 0.100 | |
| d2 | | 0.56 | | | 0.022 | |
| E | 7.37 | | 8.38 | 0.290 | | 0.330 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 5.08 | | | 0.200 | |
| F | | 0.38 | | | 0.015 | |
| G | | | 0.101 | | | 0.004 |
| M | | 1.27 | | | 0.050 | |
| M1 | | 1.14 | | | 0.045 | |



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